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APPLICATION

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FOR: EMBEDDED INDUCTOR AND METHOD OF
MAKING

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EMBEDDED INDUCTOR AND METHOD OF MAKING

BACKGROUND OF THE INVENTION

The present invention relates to the field of embedded inductors and, more particularly, relates to tunable, three dimensional embedded inductors buried in a dielectric substrate, most preferably a multilayer ceramic (MLC) substrate.

Conventional MLC structures are formed from ceramic greensheets which are prepared by mixing a composition of ceramic particulate, a thermoplastic polymeric binder, plasticizers and solvents. The ceramic particulate may contain particles of, for example, alumina, aluminum nitride, glass-ceramic, glass plus ceramic, and silicates. This composition is spread or cast into ceramic sheets or slips from which the solvents are subsequently volatilized to provide coherent and self-supporting flexible greensheets. After blanking, via formation, screening of electrically conductive vias and lines, stacking and laminating, the greensheet laminates are eventually fired at temperatures sufficient to drive off the polymeric binder resin and sinter the ceramic particulates together into a densified ceramic substrate. The metals used for the electrically conductive vias and lines are chosen to be compatible with the ceramic material and may include copper as well as refractory metals such as molybdenum and

tungsten.

MLC structures are not widely used for radio frequency and analog devices such as rf amplifiers, transformers and impedance matching networks because there have not been easy, cost effective ways to integrate inductors, transformers and the like into the MLC structure. Q is a quality factor for inductors and is defined as the ratio of its reactance to its effective series resistance at a given frequency. It would be desirable to have an embedded inductor with a relatively high Q value and high inductance.

Others have proposed various embedded inductors.

Muckelroy U.S. Patent 3,812,442, the disclosure of which is incorporated by reference herein, discloses a three dimensional inductor in which a coil is imprinted on each layer. Such a design leads to undesirable capacitance between the layers. Capacitance is undesirable because it decreases self resonant frequency. Further, due to the thinness of the metalization, there is a high resistance path resulting in lower Q.

Fleming et al. U.S. Patent 5,389,428, the disclosure of which is incorporated by reference herein, disclose a process for making surface mount inductors having ferrite cores.

Hwang et al. U.S. Patent 5,610,569, the disclosure of which is

incorporated by reference herein, disclose an embedded inductor formed of conductive strips and columns of vias. Due to overlap of the top and bottom portions of the inductor, undesirable capacitance results along with lower Q.

5 Lipkes et al. U.S. Patent 5,945,902, Sasaki et al. U.S. Patent 6,008,151, Kumagai et al. U.S. Patent 6,147,573 and Takeuchi et al. U.S. Patent 6,189,200, the disclosures of which are incorporated by reference herein, disclose embedded inductors having one turn of the coil per each layer resulting in high turn to turn capacitance.

10 Alford et al. U.S. Patent 6,008,102, the disclosure of which is incorporated by reference herein, disclose a three dimensional inductor coil fabricated on top of a semiconductor substrate. It is noted therein that the insulating core of previous prior art devices is not favored because it is too lossy for many high
15 frequency applications. Further, the inductor structure has very thin conductor lines which lead to high resistance and low Q.

 Yamamoto et al. U.S. Patent 6,104,272, the disclosure of which is incorporated by reference herein, disclose a coil which is subsequently embedded in a ceramic chip element.

20 Libertore et al. U.S. Patent 6,160,469, the disclosure of which is incorporated by reference herein, disclose a two dimensional inductor. Two dimensional inductors are not preferred

because three dimensional inductors have less conductor length per a given volume. Further, two dimensional inductors are more affected by outside fields because of the large, unprotected fringe field whereas in three dimensional inductors, a large portion of the fringe field is located within the loops which shield it.

IBM Technical Disclosure Bulletin, 29, No. 2, p. 783 (July 1986) discloses an embedded MLC coil which is used as a magnetic deflection coil for an electron beam lithography machine. Such a structure cannot be integrated in an electronic package.

Notwithstanding the above-noted work of others with respect to embedded inductors, there remains a need for an improved embedded inductor, particularly one buried or embedded in MLC.

Accordingly, it is a purpose of the present invention to have an embedded inductor having high Q and high inductance.

It is another purpose of the present invention to have an embedded inductor with low capacitance.

It is yet another purpose of the present invention to have an embedded inductor that is tunable.

These and other purposes of the present invention will become more apparent after referring to the following description

considered in conjunction with the accompanying drawings.

BRIEF SUMMARY OF THE INVENTION

The purposes of the invention have been achieved by providing, according to a first aspect of the present invention, a dielectric substrate having a multiturn inductor comprising:

a) a multilayer dielectric body comprising a plurality of layers;

b) a multiturn inductor buried within the dielectric body, each turn of the inductor comprising a bottom portion, a top portion and two side portions, the bottom portion and top portion being parallel and in different layers of the dielectric body, the side portions being parallel to each other and extending between the top and bottom portions and comprising vias in the dielectric body.

According to a second aspect of the present invention, there is provided a method of forming a dielectric substrate having a multiturn inductor, the method comprising the steps of:

a) obtaining a plurality of layers;

- b) forming conductive lines on a first group of layers;
- c) forming conductive vias in a second group of layers;
- d) forming conductive lines on a third group of layers;
- e) stacking at least one layer from the second group of layers
5 on at least one layer from the third group of layers; and
- f) stacking at least one layer from the first group of layers
on the at least one layer from the second group of layers
wherein the stacking of the first, second and third groups of
layers form an inductor buried within a dielectric substrate.

10 **BRIEF DESCRIPTION OF THE DRAWINGS**

The features of the invention believed to be novel and the
elements characteristic of the invention are set forth with
particularity in the appended claims. The Figures are for
illustration purposes only and are not drawn to scale. The
15 invention itself, however, both as to organization and method of
operation, may best be understood by reference to the detailed
description which follows taken in conjunction with the
accompanying drawings in which:

Figure 1 is a perspective view of a first embodiment of an embedded inductor according to the present invention. The dielectric material that would normally obscure the embedded inductor has been removed for clarity.

5 Figure 2 is an end view of the embedded inductor of Figure 1.

Figure 3 is an end view of a second embodiment of the embedded inductor according to the present invention.

Figure 4 is an end view of a third embodiment of the embedded inductor according to the present invention.

10 Figure 5 is an end view of a fourth embodiment of the embedded inductor according to the present invention.

Figure 6 is a perspective view of a fifth embodiment of the embedded inductor according to the present invention.

15 Figures 7A, 7B and 7C illustrate the different dielectric layers used to make the embedded inductors according to the present invention.

Figure 8 is a front view of the embedded inductor of Figure 1 illustrating the tunability of the embedded inductor.

Figure 9 is a cross sectional view of the embedded inductor of Figure 1 in its environment.

Figure 10 is a perspective view of another embodiment of an embedded inductor according to the present invention. The dielectric material that would normally obscure the embedded inductor has been removed for clarity.

Figures 11A, 11B and 11C illustrate the different dielectric layers used to make the embedded inductor of Figure 10.

Figures 12A, 12B and 12C are top views of the dielectric substrate of Figure 1 illustrating different operations for tuning the embedded inductor.

Figure 13 is a perspective view of the embedded inductor of Figure 1 with the addition of an electrically isolated plate for tuning the embedded inductor.

Figure 14 is a perspective view of the embedded inductor of Figure 1 with the addition of an electrically connected plate for tuning the embedded inductor.

Figure 15 is a cross sectional view similar to Figure 9 but also showing a second embedded inductor which together with the first embedded inductor forms a transformer.

DETAILED DESCRIPTION OF THE INVENTION

Referring to the Figures in more detail, and particularly referring to Figure 9, there is shown a cross sectional view of a dielectric substrate 10, most preferably an MLC substrate 10, having the embedded inductor 12 according to the present invention. The embedded inductor 12 may also have termination vias 24 for connecting to pads 62 on the surface of the dielectric substrate 10. There may further be power and/or ground planes 60 above and below the embedded inductor 12. The dielectric substrate 10 may further include signal wiring lines, signal redistribution planes and additional termination pads on the surfaces of the dielectric substrate 10. The latter features are not shown for clarity.

Referring now to Figures 1 and 2, there is shown the embedded inductor 12 in the dielectric substrate 10 with the ceramic material that would normally surround the embedded inductor 12 being removed. The embedded inductor 12 is essentially a multiturn coil that has an axis 14 that is parallel to the plane of each of the layers 16 that make up the dielectric substrate 10. Each turn of the coil comprises a top portion 18, a bottom portion 20 and two sides 22. As can be seen from Figures 1 and 2, the top portion 18 and bottom portion 20 are parallel and are in different layers. Thus, bottom portion 20 is in a first layer while top portion 18 is in another layer three layers away. The side portions 22, which

connect a top portion 18 to a bottom portion 20, are generally perpendicular to the layers 16 of the Dielectric substrate 10. As the embedded inductor 12 may be made by MLC or similar technology, top portion 18 and bottom portion 20 will be formed by screened
5 lines while side portions 22 comprise at least one via 32 but will usually comprise more than one via 32 as shown in Figures 1 and 2. The forming of the dielectric substrate 10 and embedded inductor 12 will be discussed in more detail hereafter. Lastly, the embedded inductor 12 has termination vias 24 which connect to other internal
10 wiring (not shown) in the dielectric substrate 10.

Advantages of the embedded inductor 12 according to the present invention include high Q, high stability with respect to temperature, humidity, time, high inductance capabilities and low space constraints. Capacitance of the embedded inductor 12 is also
15 minimized. A further advantage of the present invention is that the embedded inductor 12 may be tuned to optimize performance.

Referring now to Figure 8, a front view of the embedded inductor 12 is shown. Designing an embedded inductor 12 that produces a given amount of inductance can be done in a number of
20 ways. Inductance can be increased by decreasing the inductor loop periodicity 28 or by increasing the number of loops 30 in the embedded inductor 12. As the size of the loop increases, the height 26 and width 34 (as shown in Figure 2) of the loop increases and inductance will also increase. As the ratio of the loop height 26

to the loop width 34 approaches 1, the optimal amount of inductance is obtained for a given loop size. The width of the top portion 18 and bottom portion 20 and the diameter of the vias 32 also affect inductance. For example, as the via diameter increases, Q also increases due to a lowering of the resistivity of the loop. Similarly, as the width of the top portion 18 and bottom portion 20 increase, Q also increases.

The materials used for the ceramic material also have an effect on the self-resonant frequency of the inductor. For example, the ceramic material can be alumina or glass-ceramic. The higher the dielectric constant, the lower the self-resonant frequency. While the discussion thus far has centered on the use of ceramic materials for the dielectric substrate 10, it should be understood that organic materials, such as G10, FR4, fiberglass reinforced plastics and the like can also be used for the dielectric substrate 10. However, organic materials tend to absorb moisture which lowers the Q and can slightly affect the inductance.

Still referring to Figures 1 and 2, the top portion 18 and bottom portion 20 connecting the side portions 22 of the embedded inductor 12 have lower crosssectional area than the side portions 22 and create higher resistance. Therefore, structural changes which minimize the resistance of the top portion 18 and bottom portion 20 create higher Q values and allow the optimization of the embedded inductor 12.

One example of such a structural change is that shown in Figure 3 wherein the top portion 18 of embedded inductor 112 actually comprises top subportions 18A and 18B and bottom subportions 20A and 20B. By doubling the metal that is present in the inductor loop, the resistance of the embedded inductor 112 is reduced, thereby increasing its inductance.

Referring now to Figure 4, the embodiment shown in Figure 3 has been modified by adding vias 36 between top subportions 18A and 18B as well as between bottom subportions 20A and 20B. The addition of vias 36 to the inductor loop should further reduce the resistance and increase the Q of embedded inductor 212.

Another embodiment of the present invention is shown in Figure 5 wherein the inductor loop has been made closer to a circular shape to further increase the Q of embedded inductor 312.

The embodiments discussed thus far are variations on the embedded inductor 12 shown in Figure 1 wherein the embedded inductor 12, 112, 212, 312 has an axis 14 that is essentially a straight line. The embodiment of the present invention that is shown in Figure 6 illustrates an embedded inductor 412 that has a circular axis 15 so that the embedded inductor 412 ends up having a toroidal shape. The axis of embedded inductor 412 remains parallel to the plane of ceramic layer 16. The advantages of the toroidal-shaped inductor shown in Figure 6 are smaller external

magnetic fields and reduced unwanted coupling to adjacent components.

Referring now to Figures 7A, 7B and 7C, the method of making the embedded inductor 12 of Figure 1 will be discussed. The base layers (16 as shown in Figure 1), if any, of the dielectric substrate 10 are formed by conventional techniques as alluded to earlier. These base layers may contain various signal, ground or power wiring layers. On top of these base layers, a layer 40 having wiring lines 42 (as shown in Figure 7C) is stacked followed by the stacking-on layer 40 of one or more layers 44 having vias 46 (as shown in Figure 7B) and layer 48 having wiring lines 50 and vias 52 (as shown in Figure 7A). Vias 52 electrically connect the embedded inductor 12 to additional wiring in the dielectric substrate 10. On top of layer 48, there will usually be at least one additional wiring layer to connect the embedded inductor 12 to the top side of the dielectric substrate 10.

The process to make any of the other embedded inductors shown in Figures 3 to 6 would be the same as above except there would be additional wiring line layers 40 and 48 as well as one or more additional via layers 44.

Moreover, it should be understood that the wiring lines and via patterns shown in Figures 7A, 7B and 7C can be easily varied to facilitate any of the embedded inductor designs shown in Figures 1

through 6. For example, the via pattern of layer 44 shown in Figure 7B would be varied to form the vias 36 of embedded inductor 212 as shown in Figure 4. Additionally, the number of layers 44 would be adjusted to fit the desired size of the embedded inductor. 5 Similarly, the wiring pattern 42 in layer 40 of Figure 7C, the wiring pattern 50 and vias 52 in layer 48 of Figure 7A, and the via pattern 46 in layer 44 of Figure 7B would all have to be modified, according to the teachings of the present invention, to form the embedded inductor 412 shown in Figure 6. The modification of the 10 various layers as just discussed are well within the routine capabilities of one skilled in the art.

Another embodiment of the present invention is shown in Figure 10 in which a perspective view of an embedded inductor 70 in a dielectric substrate 10 is illustrated. Again, the dielectric material that would normally surround the embedded inductor 70 is removed. Further, the dielectric substrate 10 may further include signal wiring lines, signal redistribution planes and termination pads on the surfaces of the dielectric substrate 10. The latter features are not shown for clarity.

20 It is noted that the embedded inductor 70 has staggered via columns 70 which enable a more tightly wound structure. The embedded inductor 70 would advantageously produce high inductance values but without parasitic capacitance, thereby resulting in a high self resonant frequency. Q is maintained by double strapping

of the top wiring lines 74 and bottom wiring lines 76.

Referring now to Figures 11A, 11B and 11C, the method of making the embedded inductor 70 of Figure 10 will be discussed. The base layers (78, as shown in Figure 10), if any, of the dielectric substrate 10 are formed by conventional techniques as alluded to earlier. These base layers may contain various signal, ground or power wiring layers. On top of these base layers, at least one layer 80, and preferably at least two layers 80, having wiring lines 82 (as shown in Figure 11C) is stacked on the base layer(s) followed by the stacking of one or more layers 84 having vias 86 (as shown in Figure 11B) and at least one layer 88, and preferably at least two layers 88, having wiring lines 90 and vias 92 (as shown in Figure 11A). Vias 92 electrically connect the embedded inductor 70 to additional wiring in the dielectric substrate 10. On top of layer 88, there will usually be at least one additional wiring layer to connect the embedded inductor 70 to the top side of the dielectric substrate 10.

The embedded inductors according to the present invention are tunable, meaning that some operation can be performed on the embedded inductors that fine tunes the amount of inductance obtained. Tuning may occur, for example, by design changes (such as making the inductor closer to ideal shape or adding extra wiring lines to reduce resistance), deletion process (such as laser deletion, sand blasting, fuse links) which delete part of the

inductor, or additive processes (such as adding silver paint or copper strips) to attach more loops to the inductor. Some of these operations are illustrated in Figures 12A, 12B and 12C. For tuning the embedded inductor, it is necessary to have the top of the embedded inductor exposed on the top surface of the dielectric substrate or be able to access the top of the embedded inductor such as by laser drilling through the dielectric substrate. Referring first to Figure 12A, the top of the embedded inductor 12 is exposed such that access to wiring lines 18 is possible. Then, one of the wiring lines 18 is tapped at 94. Surface wiring line 96 is then formed, such as by silver painting or depositing a copper strip, to connect tap 94 to pad 98. Wiring line 100 connects termination via 24 to pad 102. Wiring line 100 and pad 102 were designed into the dielectric substrate when it was formed so no "post-forming" operation is necessary. By tapping the embedded inductor 12 at 94, the inductor coil has effectively been shortened. If desired, wiring line 18 may be severed, such as by laser deletion, at 104 as shown in Figure 12B. Referring now to Figure 12C, adjacent embedded inductor coils 12A and 12B have been connected to increase the inductance of the embedded inductor by adding wiring line 105, such as by silver paint or depositing a copper strip, between termination vias 24A and 24B.

An additional method of tuning the embedded inductor is illustrated in Figure 13. By placing an electrically isolated plate 106 at either end or both ends of the embedded inductor 12, the

inductance is reduced because the plate 106 is coupled magnetically to the embedded inductor 12 and intercepts the coil flux. By removing portion 108 of plate 106, such as by laser deletion, the inductance can be increased by some amount to tune a more accurate
5 inductance value. A similar result can be obtained by electrically coupling plate 106 to the embedded inductor 12, and removing portion 108 of plate 106 if desired, as shown in Figure 14.

Referring now to Figure 15, another embodiment of the present invention is illustrated. Dielectric substrate 10 has proximate,
10 parallel embedded inductors 12C and 12D which together form a transformer. The embedded inductors 12C and 12D may also have termination vias 24 for connecting to pads 62 on the surface of the dielectric substrate 10. There may further be power and/or ground
15 planes 60 above and below the embedded inductors 12C and 12D. The dielectric substrate 10 may further include signal wiring lines, signal redistribution planes and additional termination pads on the surfaces of the dielectric substrate 10 which are not shown for
20 clarity. While the inductors shown are adjacent to one another, they could be nested (for example, toroidal within a toroidal) or coaxial (for example, end to end on the same axis or partially interleaved on the same axis).

It will be apparent to those skilled in the art having regard to this disclosure that other modifications of this invention
25 beyond those embodiments specifically described here may be made

without departing from the spirit of the invention. Accordingly, such modifications are considered within the scope of the invention as limited solely by the appended claims.

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